Spectral analysis of the magnetooptical response in valley polarized $Pb_{1-x}Sn_xSe$

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Since the last century, considerable efforts have been devoted to the study of valley-degenerate narrow gap semiconductors, such as the $Pb_{1-x}Sn_xSe$ alloy. This material possesses band minima at the *L*-points of their Brillouin zone, yielding a valley degeneracy of four. However, in (111)-oriented films, it is still not fully understood how differences between the longitudinal valley, oriented along the growth axis, and the oblique valleys, oriented at an angle with respect to that axis, appear in magneto-optical infrared spectroscopy. In this work, we report a magnetooptical study on this family of alloys, focusing on an anomaly in the interband transition of the peak intensity ratio of longitudinal and oblique valleys under a magnetic field applied along the [111] direction. Based on the Mitchell-Wallis model, we provide a theoretical fit for the experimental transmission data, which quantitatively explains the spectral shape of the data at magnetic fields as high as 35 T. In particular, we attribute this anomalous peak intensity variation to the carrier density difference between the two types of valleys as well as the field-dependent thin-film interference. Our analysis also allows for the extraction of the real and imaginary parts of the dielectric function.

I. INTRODUCTION

The valley degree of freedom in semiconductors and semimetals is behind the realization and prediction of many interesting quantum states. In van-der-Waals semiconductors, the spin and valley degrees of freedom are intertwined, resulting in the ability to excite charge carriers from individual valleys with polarized light [1]. For instance, in monolaver graphene, quantum isospin ferromagnetism arises when Coulomb interactions spontaneously lift valley degeneracy [2, 3]. Similarly, in few-layer graphene systems, such as the Bernal bilayer graphene [4], rhombohedral trilayer graphene [5, 6], and twisted double bilayer graphene [7, 8], the existence of spin and valley degrees allows for the spontaneous generation of a variety of ground states featuring different spin and valley orderings. Finally, in bulk semiconductors, such as bismuth [9] and SnTe [10], various valley ordering (such as valley polarized and valley coherent states) is also expected.

While valley ordering due to interactions is attractive, it can also appear in systems where the valley symmetry is explicitly broken due to external perturbations. Therefore, it is crucial to identify the actual mechanism behind the emergence of valley symmetry-breaking states, a task that is by no means straightforward. For bulk semiconductors, optical measurements are routinely used to probe the possible existence of various symmetrybreaking states. However, most experiments only focused on the peak positions, which indicate selection rules in absorption spectra. Whether the peak intensity can help uncover the mechanism of symmetry-breaking patterns is an important and interesting question.

In this work, we study this very question in the IV-VI material $Pb_{1-x}Sn_xSe$, which is a semiconductor that hosts three-dimensional massive Dirac fermions and offers a platform to study the valley degree of freedom as the electronic band structure is tuned. Varying temperatures and chemical composition allow one to tune the energy gap, band velocity, and Fermi surface anisotropy of these materials [11]. They were among the first reported topological crystalline insulators [12, 13] and were later studied as a model system to elucidate the properties of mirror-symmetry protected topological surface states [14, 15]. However, the interest in quantum Hall and Landau-level physics in IV-VI materials precedes the era of topological phases of matter. The high mobility of PbTe and other IV-VI materials allowed a thorough mapping of their low-energy band structure parameters through Landau level spectroscopy [11, 16–19].

The band minima in $Pb_{1-x}Sn_xSe$ is located at the Lpoints of the Brillouin zone. The 3D Fermi surface of these materials consists of four ellipsoids with their great axis oriented along $\langle 111 \rangle$ axis, as shown in Fig. 1(a). In (111)-oriented layers, Fermi surface anisotropy yields two types of valleys. Among them, the valley aligned with the growth axis (the [111] direction) is known as the longitudinal valley, while the other three valleys, oriented at an angle with the growth axis, are known as the oblique valleys. The Landau levels of bulk IV-VI semiconductors have been extensively studied using magnetooptical infrared spectroscopy (MIRS). This technique is an established tool to extract the band parameters of electrons in solids by probing optical transitions between Landau levels [11, 20–22]. However, information pertaining to the spectral shape of magnetooptical spectra has been overlooked in most experiments.

The focus of this paper is to investigate a ubiquitous spectral anomaly that appears in the relative peak intensity of magnetooptical transitions between the longitu-



FIG. 1. (a) Sketch of the oblique and longitudinal valleys of $Pb_{1-x}Sn_xSe$. (b) Relative transmission T(B)/T(0) for Sample S1 with x = 0.07. Transitions from different valleys are marked by red (oblique) and black (longitudinal) arrows. Labeled spectra for specific fields are plotted in orange for clarity. (c) Landau level fan chart extracted from the spectra in (b) and fitted by Eq. (6). Interband transitions between Landau levels N and N + 1 are labeled on the right.

dinal and oblique valley levels in $Pb_{1-x}Sn_xSe$ samples with a doping percentage x < 0.16. Despite the expected three-to-one degeneracy ratio, our experimental observation shows that the optical transitions between low-index Landau levels are shown to violate this ratio. Such a spectral anomaly has been observed in the same family of materials in previous experiments but never studied [11, 19]. To resolve this puzzle, we develop a theoretical model to capture the spectral response of the Landau level transitions. By applying this method to analyze our experimental data obtained for (111)-oriented $Pb_{1-x}Sn_xSe$ epilayers, we find that the anomalous intensity ratio arises from two important factors: the carrier density difference between the two types of valleys (i.e., valley polarization) and the field-dependent thinfilm interference effects. When included, the model accurately reproduces our data, allowing the extraction of a disorder-broadening parameter and vielding the relative carrier population for each valley. Through this analysis, the real and imaginary parts of the dielectric function are also extracted. Our theoretical approach provides a comprehensive framework for understanding the anomalous peak intensity in thin-film interference magnetooptical spectroscopy of IV-VI semiconductors and elucidates the actual mechanism behind valley ordering in our sample.

The structure of the paper is the following: In Section II, we build up an effective Hamiltonian and extract the model parameters from the Landau fan diagram obtained from the experiment. In Section III, we analyze the magnetooptical spectroscopy data and explain the observed anomalous peak intensity ratio variations. In Section IV we provide additional discussions on the results and conclude the paper.

II. THE LANDAU FAN DIAGRAM

Experimentally, we carry out MIRS measurements using a setup at the National High Magnetic Fields Lab (NHMFL) that couples an FTIR spectrometer with a cryostat, enabling measurements up to B = 35 T and down to T = 5 K. The measurement is set up in Faraday geometry [23], and the transmission signal is collected by a bolometer behind the sample. In this work, we report measurements on two samples, S1 and S2, both of which are grown on BaF₂ (111) substrate by molecular beam epitaxy.

Figure 1(b) shows magnetooptical spectra taken on $Pb_{1-x}Sn_xSe$ with x = 0.07 (Sample S1). By dividing the transmission spectra T(B) by the spectra measured at zero magnetic field T(0), we extract the relative transmission that contains only field-dependent transitions. The relative transmission exhibits a set of minima that shift to higher energies with increasing magnetic field originating from interband transitions between the Landau levels of the conduction and valence band. From the spectra, we can construct a Landau level fan chart shown in Fig. 1(c), where the energy of peak minima in Fig. 1(b) is re-plotted as a function of the magnetic field.

A. The $k \cdot p$ model for $Pb_{1-x}Sn_xSe$

To understand the observed Landau fan diagram, we theoretically introduce the $k \cdot p$ Hamiltonian for

 $Pb_{1-x}Sn_xSe$ near the four *L*-points [24–28],

$$H(\mathbf{k}) = \begin{bmatrix} -\varepsilon_k & 0 & \hbar v_z k_z & \hbar v_c k_- \\ 0 & -\varepsilon_k & \hbar v_c k_+ & -\hbar v_z k_z \\ \hbar v_z k_z & \hbar v_c k_- & \varepsilon_k & 0 \\ \hbar v_c k_+ & -\hbar v_z k_z & 0 & \varepsilon_k \end{bmatrix}.$$
(1)

In the above equation, $\varepsilon_k \equiv \Delta + \hbar^2 k_{\perp}^2/2m$, v_z is the velocity along the z-axis (which is parallel to the [111] direction), $k_{\pm} = k_x \pm i k_y$, $k_{\perp}^2 = k_x^2 + k_y^2$, v_c is the velocity in the x-y plane, and m represents the contribution from the far bands to the effective mass. We ignored a potential k_z^2 term in ε_k , as its contribution is much smaller than the other terms [28].

In the presence of a strong perpendicular magnetic field, Landau levels appear in the energy spectra. After applying the Peierls substitutions and some simplifications [27], we can write the effective Hamiltonian as

$$H_B(N,k_z) = \begin{bmatrix} -\Delta - \hbar\omega_S N_- & 0 & \hbar v_z k_z & \hbar\omega_R \sqrt{N} \\ 0 & -\Delta - \hbar\omega_S N_+ & \hbar\omega_R \sqrt{N} & -\hbar v_z k_z \\ \hbar v_z k_z & \hbar\omega_R \sqrt{N} & \Delta + \hbar\omega_S N_- & 0 \\ \hbar\omega_R \sqrt{N} & -\hbar v_z k_z & 0 & \Delta + \hbar\omega_S N_+ \end{bmatrix}$$
(2)

The above Hamiltonian is written in the basis $\left[V^{\frac{1}{2}}|N-1\rangle, V^{-\frac{1}{2}}|N\rangle, C^{\frac{1}{2}}|N-1\rangle, C^{-\frac{1}{2}}|N\rangle\right]$, where V and C denote the valence and conduction bands, respectively, and the superscripts $\pm 1/2$ denote the two eigenstates that form a Kramers pair in this subspace. In the above Hamiltonian, N is the Landau level index, $N_{\pm} \equiv N \pm 1$, and Δ is half the band gap. We have also introduced the relativistic energy $\hbar\omega_R = \sqrt{2\hbar e B v_c^2}$ and the non-relativistic energy $\hbar\omega_S = \hbar e B/m$.

The eigenvalues of the above Hamiltonian are

$$\begin{cases} E_{\lambda=\pm,N,\xi=\pm}(k_z) = \lambda \sqrt{P_{N,\xi}^2 + \hbar^2 v_z^2 k_z^2}, & N > 0\\ E_{\lambda=\pm,0,\xi=+}(k_z) = \lambda \sqrt{P_{0,\xi=+}^2 + \hbar^2 v_z^2 k_z^2}, & N = 0 \end{cases},$$
(3)

where

$$P_{N,\xi=\pm} = \xi \hbar \omega_S + \sqrt{N \hbar^2 \omega_R^2 + (\Delta + N \hbar \omega_S)^2}.$$
 (4)

Here, $\lambda = \pm 1$ labels the conduction and valence band, respectively, and $\xi = \pm 1$ is the index that represents the Kramers pair $s = \pm 1/2$. The corresponding eigenstates will be denoted as $|\lambda, N, \xi, k_z\rangle$

B. Extracting model parameters

The above $k \cdot p$ model can now be used to understand the Landau fan chart in Fig. 1(c). In particular, each dot in the fan chart corresponds to the peak of an interband transition characterized by $k_z = 0$ and the selection rule $\Delta N = \pm 1$ and $\Delta s = \pm 1$. Moreover, the following transitions have the same peak energy $(k_z = 0)$:

(i)
$$|\lambda = -, N, \xi = -\rangle \rightarrow |\lambda = +, N + 1, \xi = +\rangle$$
,
(ii) $|\lambda = -, N, \xi = +\rangle \rightarrow |\lambda = +, N + 1, \xi = -\rangle$,
(iii) $|\lambda = -, N + 1, \xi = -\rangle \rightarrow |\lambda = +, N, \xi = +\rangle$,
(iv) $|\lambda = -, N + 1, \xi = +\rangle \rightarrow |\lambda = +, N, \xi = -\rangle$. (5)

As a result, we will use the symbol (N - N+1) to denote the collection of these transitions. Such considerations yield the following energy for the (N - N+1) interband transition [23, 29]:

$$\Delta E = \sqrt{(\Delta + (N+1)\hbar\omega_S)^2 + (N+1)\hbar^2\omega_R^2} + \sqrt{(\Delta + N\hbar\omega_S)^2 + N\hbar^2\omega_R^2}, \qquad (6)$$

which are plotted as solid lines in Fig. 1(c). By fitting the solid lines with the experimental data, we obtain the model parameters in Table I.

The magnetooptical spectra also allow us to extract the Fermi energy E_F in each valley. Specifically, in the presence of a strong magnetic field, the *p*-type carrier density of the system can be written as

$$n(E_F) = \frac{g_L}{S} \sum_{N,\xi} \int_{-\infty}^{\infty} f(E_{\lambda,N,\xi}(k_z)) \frac{dk_z}{2\pi}$$
(7)
$$= \frac{1}{2\pi^2 l_B^2} \frac{1}{\hbar v_z} \sum_{N,\xi} \sqrt{E_F^2 - P_{N,\xi}^2} \Theta(-|P_{N,\xi}| - E_F),$$

where $g_L = S/2\pi l_B^2$ is the degeneracy of each Landau level with $l_B = \sqrt{\hbar/eB}$ being the magnetic length, and S is the cross-section area of the sample perpendicular to the magnetic field. Moreover, the Fermi-Dirac distribution $f(E_{\lambda,N,\mathcal{E}}(k_z))$ is taken to be a step function in the zero-temperature limit. Because we have obtained the carrier density in each valley, the Fermi level can be uniquely determined from Eq. (7) at different magnetic fields. The variation of the Fermi level as a function of the magnetic field is shown in Fig. 2. We can see that the longitudinal valley enters the quantum limit, where only the lowest Landau level is occupied, at a much smaller magnetic field than oblique valleys. After determining the carrier density of the sample, we find that the populations of carriers from different valleys are uneven, as shown in Table I. This kind of difference has been attributed to the thermal strain between the substrate BaF_2 and lead salts [30, 31]. A similar splitting resulting from lattice strain has recently enabled the observation of a valley-polarized quantum Hall effect in IV-VI quantum wells [32].

	Symbol	$\Delta({\rm meV})$	$v_c(10^5\mathrm{m/s})$	$v_z^* (10^5 \mathrm{m/s})$	$m(m_e)$	p -type $(10^{17} \mathrm{cm}^{-3})$ per valley	g_v	d(nm)
Sample S1 ($x = 0.07$)	Longitudinal	25	5.20	4.11	0.25	0.40	1	518
	Oblique	25	4.70	5.14	0.30	3.20	3	518
Sample S2 ($x = 0.10$)	Longitudinal	28	5.38	4.19	0.40	1.10	1	990
	Oblique	28	4.83	5.32	0.40	2.00	3	990

 v_z is derived from the x-y plane velocity v_c of longitudinal and oblique valleys [11].



FIG. 2. Landau level spectra of the Sample S1. (a) and (b) show the longitudinal and oblique valleys, respectively. In particular, we use (λ, N, ξ) to label each Landau level. The blue (red) lines illustrate the Landau level with the index $\xi = +1$ (-1). Moreover, the black line in each figure marks the position of the Fermi level. (c) Without the magnetic field, the thermal strain results in the different populations of holes in different valleys. The dashed line illustrates the position of the Fermi level at B = 0.

III. ANAMOLOUS PEAK INTENSITY RATIO IN THE MAGNETOOPTICAL SPECTRA

One of the most interesting features in the experimental data is the anomalous peak intensity ratio variations, which we discuss in this section.

A. Peak intensity ratio variations in the experiment

In Fig. 1(b), we have marked the (0 - 1), (1 - 2) and (2- 3) interband transition peaks according to Fig. 1(c). Peaks from the intraband cyclotron resonances (CR) may be present at lower energies at 35 T, which quickly merges into the noise region and cannot be extracted reliably. Transitions corresponding to oblique and longitudinal valleys are marked by red and black arrows, respectively. Because the oblique valleys are three-fold degenerate $(q_v = 3)$ and the longitudinal valley is non-degenerate $(q_v = 1)$, one would have naively expected that the peak intensity of magnetooptical transitions from the oblique valley to be close to three times stronger than those from the longitudinal valley. However, it is evident from Fig. 1(b) that while the (2 - 3) transition roughly follows this expectation, the (1 - 2) transition does not. The latter transition violates this ratio over the entire magnetic field range.

We can confirm that this anomalous peak intensity ratio variation is an intrinsic property of the material. For example, Fig. 3(a) presents magnetooptical spectra measured for another sample S2 at 17 T. The anomaly seen in Sample S1 for the (1 - 2) transition is clearly reproduced in this second sample. Additionally, Fig. 3(b) demonstrates that the reproducibility of the spectral shape seen in Fig. 1(b) for measurements taken on two different setups at the NHMFL (a 35 T resistive magnet and a 17.5 T superconductor coil).

Figure 3(c) plots the ratio between the integrated peak intensity of the oblique and the longitudinal valley transitions for the (1 - 2) and (2 - 3) transitions. The integrated peak intensity is extracted by performing a Gaussian fit and taking the integral over the fitted function in a narrow range of energies spanning each transition. We should note that the uncertainty of such a fit is influenced by the definition of the baseline of the spectra. Thus, it only serves as a means of extracting the changing trend



FIG. 3. (a) Comparison of the spectra acquired at 17T for samples S1 and S2. (b) Comparison between the spectra obtained at 10 T, 12.5 T, 15 T and using two different MIRS setups for the sample S1. The spectra between the two setups are manually shifted for better shape comparison. (c) Peak area ratio between the oblique and longitudinal valley. The blue and purple data points (measured in different setups) correspond to the (1 - 2) interband transition, and the yellow and orange data points correspond to the (2 - 3) interband transition.



FIG. 4. The theoretically calculated real and imaginary part of the (a) conductivity σ and (b) dielectric function ε at B = 1 T and B = 35 T. These results are obtained by averaging over left-handed and right-handed circular polarized light. The unit conductivity $\sigma_0 = e^2/8\pi\hbar l_B$ is calculated at B = 1 T. (c) The magnetooptical spectra of the sample S1. The black and red lines correspond to the experiment and theory, respectively. The dashed box highlights the anomalous peak intensity variations of the (1 - 2) interband transition.

of the ratio versus magnetic fields and does not represent the value of the real ratio. However, it is evident from this fit that the integrated peak intensity ratio for the (1 - 2) transition is significantly smaller than that found for the (2 - 3) transition.

B. Optical conductivity and transmission

In order to understand the observed peak intensity ratio variations, we need to calculate the theoretical transmission spectra based on the model in Eq. (2). In general, the transmission properties of a bulk semiconductor are related to its dielectric function, which can be written generally as [33]

$$\varepsilon = \varepsilon_{\rm core} + i \frac{\sigma}{\omega \varepsilon_0},$$
(8)

where σ is the (complex) conductivity of the material, ω is the frequency of the incident light, and ε_0 is the vacuum permittivity. $\varepsilon_{\text{core}}$ represents the contributions from far bands outside our energy window. In this work, we take $\varepsilon_{\text{core}} = 21$ [34].

Based on the Kubo formula, the dynamical conductivity for the right-handed (+) and the left-handed (-)circularly polarized light can be written as

$$\sigma_{\pm}(\omega) = \frac{g_L g_v e^2 \hbar}{i \mathcal{V}} \sum_{\alpha,\beta} \frac{f(E_{\alpha}) - f(E_{\beta})}{E_{\alpha} - E_{\beta}} \frac{|\langle \alpha | \hat{v}_{\pm} | \beta \rangle|^2}{E_{\alpha} - E_{\beta} + \hbar \omega + i \Gamma}$$
(9)

where \mathcal{V} is the volume of the sample, $g_v = 1$ and $g_v = 3$ are the degeneracy of the longitudinal and oblique valley, respectively, and ω is the frequency of incident light. In addition, α and β label all eigenstates $|\lambda, N, \xi, k_z\rangle$. The velocity operator $\hat{v}_{\pm} = \hat{v}_x \pm i\hat{v}_y$ are defined as $\hat{v}_x = \partial H/\partial p_x$, $\hat{v}_y = \partial H/\partial p_y$. Finally, Γ is a broadening parameter. When we fit the experimental data with our formula, we found that the broadening parameter Γ is best taken to be $\Gamma(\hbar\omega) = a + b\hbar\omega$, where a and b are fitting parameters. Further details for using this dynamic broadening model are provided in Appendix B.

In Fig. 4(a), we present the numerically calculated conductivity of the sample at two different magnetic fields of B = 1 T and B = 35 T. At B = 1 T, the real part of the conductivity Re[$\sigma(\omega)$] has two interesting features. First, it shows a sudden increase for $\hbar\omega \sim 150$ meV, which is due to the absorption edge. Second, it approaches a linear function of the photon frequency in the highfrequency limit. At B = 35 T, the whole curve starts to oscillate around the B = 1 T case. Note that we label the intraband cyclotron resonance as CR in the figure, which mainly arises from the intraband transitions between the N = 0 and N = 1 Landau levels in the valence band.

Next, we consider the dielectric function shown in Fig. 4(b), which inherits many features from the conductivity. For example, because $\text{Im}[\varepsilon] = \text{Re}[\sigma]/\omega\varepsilon_0$, the asymptotic behavior of $\text{Re}[\sigma] \sim \omega$ produces a constant $\text{Im}[\varepsilon] = 5.5$. Meanwhile, we introduce two important optical constants, the refractive index \bar{n} and the optical extinction coefficient k. They are related to the dielectric function ε as

$$\bar{n} = \sqrt{\frac{|\varepsilon| + \operatorname{Re}[\varepsilon]}{2}}, \quad k = \sqrt{\frac{|\varepsilon| - \operatorname{Re}[\varepsilon]}{2}}.$$
 (10)

With the dielectric function at hand, we can finally obtain the slab transmission as [35, 36]

$$T(B) = e^{-Ad} \frac{(1 - |r|^2)^2 + 4|r|^2 \sin^2(\phi_r)}{(1 - |r|^2 e^{-Ad})^2 + 4|r|^2 e^{-Ad} \sin^2(\alpha d + \phi_r)},$$
(11)

where d is the thickness of the sample, and all other parameters are functions of \bar{n} and k. Specifically, $\alpha = \omega \bar{n}/c$, and $A = 2\omega k/c$ is the absorption coefficient. In addition, |r|, ϕ_r in Eq. (11) are the amplitude and phase of the half-space reflection coefficient r, respectively, defined as

$$r = \frac{1 - (\bar{n} + ik)}{1 + (\bar{n} + ik)}.$$
(12)

A brief derivation of Eq. (11) is given in Appendix A.

By combining the above Eq. (8)-(12), we can obtain the theoretical results for the magnetooptical transmission of the sample, which are shown in Fig. 4(c). Note that here we plot $T_{\text{unpolarized}} = (T_+ + T_-)/2$ because the experimental data is obtained using an unpolarized light source. As demonstrated in the figure, there is a good agreement between our theory and the experimental data.

C. The (1 - 2) interband transition

Having achieved a general agreement between the theory and the experimental data, we now focus on the (1 - 2) interband transition, which is one of the most interesting features in our data. A dashed box in Fig. 4(c) highlights this part of the data.

First, this part of the data arises from the group of four transitions labeled as (1 - 2), as defined in Eq. (5). Second, note that there are two dips inside the dashed box, the left of which belongs to the oblique valley and the other to the longitudinal valley. Most interestingly, the two dips initially have a similar magnitude at B = 15 T but become highly uneven at B = 35 T. This is surprising because one might expect the magnitude of the oblique valley dip to be three times that of the longitudinal valley dip. After all, the material has three oblique valleys and only one longitudinal valley.

We attribute this surprising feature to two factors. First, the carrier densities in the two valleys are significantly different. As shown in Table I, the carrier density in the oblique valley is almost eight times that of the longitudinal valley. Therefore, as the magnetic field strength increases, the longitudinal valley reaches the quantum limit at $B = 4 \,\mathrm{T}$ while the oblique valleys do not reach the quantum limit until $B = 20.5 \,\mathrm{T}$. The very different movements of the Fermi energy in the two valleys as a function of the magnetic field [see Fig. 2] causes the peak intensity ratios to deviate appreciably from 3:1. However, this is not the only reason. In fact, the thickness dof the sample also plays an important role in determining the pattern of the peak intensity ratio. In Fig. 5, we present the transmission spectra as a function of thickness at B = 35 T. Notably, a small change in the thickness of about 20% significantly alters the shape of the spectra near the (0 - 1) and (1 - 2) interband transition.

It is instructive to compare the slab transmission formula in Eq. (11) with the Beer-Lambert law $T = e^{-Ad}$, which has been widely used to explain the transmission data in bulk semiconductors. We note that the Beer-Lambert law only applies to thick samples, while Eq. (11) is much more general. To better elucidate their differences, we present a simplified version of Eq. (11),

$$T = \frac{(1 - |r|^2)^2}{e^{Ad} - 2|r|^2 \cos(2\alpha d)},$$
(13)

which is obtained by noting that $\bar{n} \gg k$, $|r| \approx 0.67$, $\phi_r \approx -\pi$ in our sample (see Appendix C for more details). In our sample, we have $Ad \in (0.04, 1.30)$, and thus, we cannot simply apply the Beer-Lambert law. Instead, the factor $\cos(2\alpha d)$ plays an important role, leading to a strong modulation between the longitudinal and oblique valleys. This is why a slight change in sample thickness could yield an appreciable variation in the peak intensity ratio between these two valleys. Such a feature is a direct manifestation of the field-dependent thin-film interference. Note that the importance of thin-film interference is also emphasized in the literature in the B = 0case [37]. The Beer-Lambert law is recovered only in the limit $Ad \gg 1$, or $d \gg A^{-1} = c/(2\omega k)$. For example, from the plot of k in our sample shown in Fig. 8(b), we estimate that the Beer-Lambert law only applies to samples with thickness $d > 2.0 \,\mu\text{m}$ in the frequency range of $\hbar \omega > 200 \,\mathrm{meV}.$

To further test our theory, we apply the same calculation to another sample (S2), which has a different composition and thickness. The fitting results are also satisfactory and can be found in Appendix D.

IV. DISCUSSION AND CONCLUSION

Although such an anomalous peak intensity ratio variation has been observed in other samples, there are a few reasons why it is particularly prominent in our sample. First, the contributions from the longitudinal and oblique valleys should be well separated in the transmission spectra so that we can distinguish the contributions from the two types of valleys. This condition is usually satisfied in the topologically trivial regime of $Pb_{1-x}Sn_xSe \ (x < 0.16)$ because the Fermi surfaces of the four L valleys have an ellipsoid shape [11, 38]. Therefore, the longitudinal valley and the oblique valleys have very different v_c . In contrast, in the topologically nontrivial regime of $Pb_{1-x}Sn_xSe$ (x > 0.16), the Fermi surfaces of the four L valleys become spherical, and hence the differences between the longitudinal and oblique valleys cease to exist [11]. As a result, these anomalous peak intensity ratio variations can be difficult to observe in the topologically nontrivial region [39].

To summarize, in this work, we carried out a detailed experimental and theoretical study of magnetooptical spectroscopy in the $Pb_{1-x}Sn_xSe$ alloy system. In particular, we focus on the peak intensity ratio variations of the interband transition, which is often neglected in the literature. We developed a theoretical model to describe the



FIG. 5. Theoretical transmission spectra at B = 35 T with varying sample thicknesses (red dashed or solid lines). We find that the sample thickness strongly influences the shape of the spectra. We also append the experimental data of sample S1 as a black line for reference. By comparing the overall shape of the experiment and theoretical results, we can confirm that a small change of thickness of about 20% significantly alters the shape of the spectra near the (0 - 1) and (1 - 2) interband transition.

fine structures in the interband transition, which helped us extract the dielectric function of the sample. The fitting between the experiment and theory is satisfactory. The analysis allows us to attribute anomalies in the spectral shape of the magnetooptical spectra to an uneven valley population and the impact of the field-dependent thin-film interference. Even in micron-thick epilayers of IV-VI materials, the uneven valley population could arise from the thermal strain resulting from the thermal expansion coefficient mismatch between the substrate and the layers. Such thermal strain is known to cause a splitting between the longitudinal and oblique valleys [30]. Meanwhile, the field-dependent thin-film interference is most pronounced when the material thickness is sufficiently small.

Our work sheds light on whether the peak intensity can help identify symmetry-breaking patterns in a sample. By carrying out a thorough theoretical and experimental analysis, we identify a large carrier density difference between longitudinal and oblique valleys in our sample. The fact that a single-particle model provides sufficient evidence to explain the anomalous peak intensity ratio leaves little room for spontaneous symmetry breaking in our sample. Our work demonstrates that sample thickness could complicate the analysis. Therefore, a careful analysis is needed to understand the spectral shape.

Our model provides a crucial foundation for identi-

fying other fine structures in the interband transition region resulting from different mechanisms. However, there are still unanswered questions that require further investigation. First, there exists a deviation of T(B)/T(0) between the experimental results and our calculations in the low-frequency regime, such as the $120 \text{ meV} < \hbar \omega < 190 \text{ meV}$ window for the B = 20 Tcurve in Fig. 4(c). This is likely due to the existence of an absorption edge within this energy window. Such a disagreement has also been observed in other experiments [39]. Meanwhile, it will be interesting to carry out a similar study for $Pb_{1-x}Sn_xTe$. We anticipate that some of the features in our sample will be even more pronounced in those samples because the difference between the v_c in the longitudinal and oblique valleys is much larger.

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Appendix A: Derivation of the slab transmission

In this appendix, we briefly explain how to derive the slab transmission formula in Eq. (11).

We start by considering the geometry shown in Fig. 6, which depicts the general process of a light incident from the helium gas, going through the sample and the substrate, and is eventually received by the bolometer behind the substrate. Under this geometry, the complex transmission coefficient τ can be obtained by summing up the contributions from the incident beam's multiple reflections in the film, which yields

$$\tau = \frac{\sum_{m=0}^{\infty} E_{t,m}}{E_i} = t_{01} t_{12} e^{i\delta} \sum_{m=0}^{\infty} (r_{12} r_{10} e^{2i\delta})^m$$
$$= \frac{t_{01} t_{12} e^{i\delta}}{1 - r_{12} r_{10} e^{2i\delta}}.$$
(A1)

In the above equation, r_{jk} and t_{jk} are the Fresnel coefficients, and j and k label the layer indices of the media shown in the figure. Moreover, δ is the phase accumulated by the incident light when it goes through the film



FIG. 6. A sketch of the incidence of a beam with multiple reflections inside a plane-parallel slab of thickness d. Here, L = 0, 1, 2 labels the index of the layer. In addition, $E_i, E_{r,m}$, $E_{t,m}$ label the incident, multiple reflected and transmitted light, respectively.

once. In the normal incident case, the phase is given by $\delta = qd = (\alpha + iA/2)d$, where A and α were introduced in Eq. (11). In addition, the Fresnel coefficients are reduced to

$$r_{jk} = \frac{\sqrt{\varepsilon_j} - \sqrt{\varepsilon_k}}{\sqrt{\varepsilon_j} + \sqrt{\varepsilon_k}}, \ t_{jk} = \frac{2\sqrt{\varepsilon_j}}{\sqrt{\varepsilon_j} + \sqrt{\varepsilon_k}}, \qquad (A2)$$

In the absorbing media, the complex refractive index is defined as $\sqrt{\varepsilon} = \bar{n} + ik$. Note that the refractive index of the substrate BaF₂ in the far infrared regime varies from 1.01 to 1.46 [40], which is almost transparent. Meanwhile, the refractive index of the helium gas is also close to the vacuum. Therefore, it is reasonable to simplify our model by assuming that the film is surrounded by the vacuum on both sides [35]. Notice that now $r_{kj} = -r_{jk}$, $r_{01} = -r_{12} = r$, $t_{12} = 1 - r$, $t_{01} = 1 + r$ we then obtain the complex transmission as

$$\tau = \frac{t_{01}t_{12}e^{i\delta}}{1 + r_{12}r_{01}e^{2i\delta}} = \frac{(1 - r^2)e^{i\delta}}{1 - r^2e^{2i\delta}}.$$
 (A3)

By substituting the relations $r = |r|e^{i\phi_r}$, we finally obtain the expression for the slab transmission as [35]

$$T = \tau \tau^*$$

= $e^{-Ad} \frac{(1 - |r|^2)^2 + 4|r|^2 \sin^2(\phi_r)}{(1 - |r|^2 e^{-Ad})^2 + 4|r|^2 e^{-Ad} \sin^2(\alpha d + \phi_r)},$

which is exactly Eq. (11) in the main text.

Appendix B: Details of the numerical procedure

In this appendix, we highlight a few notable details from our numerical calculations.

First, to avoid numerical difficulties when calculating the Landau level at a zero magnetic field (B = 0), we approximate T(0) with T(B = 1 T) [39]. In practice, it is sufficient to keep all Landau levels below a maximum Landau level index $N_{\text{max}}(B)$, which is taken to



FIG. 7. Differences between a constant and a dynamical broadening parameter at B = 35 T. The black line illustrates the experimental data of Sample S1. The red line is the theoretical transmission spectra obtained with a dynamical broadening parameter $\Gamma(\hbar\omega) = 2 \text{ meV} + 0.027\hbar\omega$. The blue dashed line represents the theoretical transmission spectra obtained with a constant broadening parameter $\Gamma = 10 \text{ meV}$.

include all inter-Landau level transitions below 800 meV. This approximation has been verified against experimental data. Moreover, the limit of the k_z integral is capped at $k_{z,\max} = 20 \text{ nm}^{-1}$.

We now comment on the broadening parameter Γ in the Kubo formula for conductivity, Eq. (9). Based on the empirical rule for the interband magnetooptical transitions in graphene [41, 42], we choose $\Gamma(\hbar\omega) = a + b\hbar\omega$ [39]. In Fig. 7, we compare the results in sample S1 using a constant broadening parameter $\Gamma = 10 \text{ meV}$ with those obtained with the full dynamical broadening parameter $\Gamma(\hbar\omega) = 2 \,\mathrm{meV} + 0.027 \hbar\omega$. It is evident that the dynamical broadening parameter fits better with the experimental data across the entire spectra. Although the constant broadening parameter of $\Gamma = 10 \text{ meV}$ fits the data very well in the energy window between 300 meV and 350 meV, it fails to capture the low-energy regime. Therefore, we used the full dynamical broadening parameter in the results shown in the main text. Meanwhile, we find that the same form of Γ also works well for the other sample (S2), where we found that $\Gamma(\hbar\omega) =$ $1 \,\mathrm{meV} + 0.027 \hbar \omega$.

Appendix C: Additional discussions on the optical coefficients for Sample S1

Apart from the dielectric function shown in the main text, it is instructive to study other optical constants, including the refractive index \bar{n} , the optical extinction coefficient k, and the half-space reflection coefficient r. These quantities are plotted in Fig. 8. We can see that these optical constants satisfy the following relations: $\bar{n} \gg k$, $|r| \approx 0.67$ and $\phi_r \approx -\pi$.

In addition, at B = 1 T, both \bar{n} and |r| show two peaks at small photon energies, corresponding to the absorption edge of the longitudinal and oblique valleys, re-



FIG. 8. In this figure, we present theoretically calculated (a) refractive index \bar{n} , (b) extinction coefficient k, (c) amplitude, and (d) phase of the half-space coefficient r of the sample S1. These results are obtained by averaging over left-handed and right-handed circular polarized light.

spectively. The fact that the dispersion of the refractive index will display peaks at the absorption edge has been reported in the previous literature [43]. Meanwhile, the extinction coefficient k displays two steep increases at the same position and keeps flat over photon energy 200 meV < E < 460 meV.



FIG. 9. The magnetooptical spectra of the sample S2. The black and red lines correspond to the experimental data and theoretical results, respectively.

Appendix D: Fitting results for Sample S2

Here, we comment on the experimental data in the other sample S2, which has a Sn concentration of x = 0.10 and a thickness of 990 nm. On the theoretical side, we applied the same procedure to this sample. The model parameters are shown in Table I. It is notable that the thickness of this sample is almost twice that of the other

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sample. With a slightly different choice of the broadening parameter $\Gamma(\hbar\omega) = 1 \text{ meV} + 0.027\hbar\omega$, we can achieve a good agreement with the experimental data for this sample. In particular, the anomalous variation of the peak intensity ratios for the (1 - 2) transition is also well captured. This agreement demonstrates that our theory is general and can be applied to different samples of this material.

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